

CDMA/AMPS RX FRONT-END GaAs MMIC

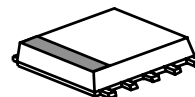
DESCRIPTION

NJG1712KC1 is a front-end MMIC including a LNA, a local amplifier and a mixer, designed mainly for 800MHz band CDMA/AMPS.

The performance of mixer and the parts count of external circuits may be optimized during development.

The ultra small & ultra thin FLP10-C1 package is applied.

PACKAGE OUTLINE



FEATURES

- Low Voltage Operation +2.8V typ.
- Low Current Consumption 15.0mA typ.
- Ultra Small & Ultra Thin package FLP10-C1 (Mount Size: 2.8x3.0x0.75mm)

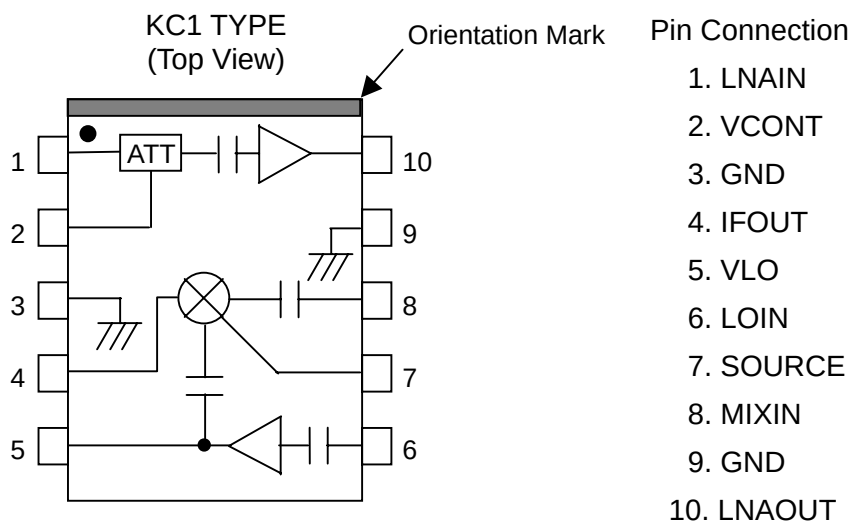
•LNA

- High Small Signal Gain 18.0dB typ.
- Low Noise Figure 1.3dB typ.
- High Input IP3 +4.0dBm typ. @ $V_{CONT}=1.9V$
+26dBm typ. @ $V_{CONT}=0.1V$

•Mixer

- High Conversion Gain 10.0dB typ.
- Low Noise Figure 6.5dB typ
- High Input IP3 +6.0dBm typ.

PIN CONFIGURATION



NJG1712KC1

■ABSOLUTE MAXIMUM RATINGS

(T_a=+25°C, Z_s=Z_i=50Ω)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
LNA Voltage	V _{LNA}		6.0	V
Gain Control Voltage	V _{CONT}		4.0	V
Mixer Voltage	V _{MIX}		6.0	V
LOCAL Amplifier Voltage	V _{LO}		6.0	V
Input Power 1	P _{LNAIN}	V _{LNA} =2.85V	+20	dBm
Input Power 2	P _{MIXIN}	V _{MIX} =V _{LO} =2.8V	+10	dBm
Input Power 3	P _{LOIN}	V _{MIX} =V _{LO} =2.8V	+10	dBm
Power Dissipation	P _D		550	mW
Operating Temperature	T _{opr}		-40~+85	°C
Storage Temperature	T _{stg}		-55~+125	°C

■ELECTRICAL CHARACTERISTICS 1 (LNA)

GENERAL CONDITIONS: T_a=+25°C, V_{LNA}=2.8V, V_{MIX}=V_{LO}=0V, f_{RF}=850MHz
P_{RF}=-30dBm, Z_s=Z_i=50Ω, with the test circuit

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Frequency	Freq		830	850	870	MHz
LNA Voltage	V _{LNA}		2.7	2.8	4.5	V
Gain Control Range	V _{CONT}		0.0	1.9	3.0	V
LNA Operating Current	I _{LNA}	P _{RF} OFF	-	6.3	7.5	mA
Small Signal Gain	Gain	V _{CONT} =1.9V	14.0	15.0	16.0	dB
Gain Flatness	G _{flat}	f _{RF} =869~894MHz	-	0.5	1.0	dB
Dynamic Range	G _{CONT}	V _{CONT} =0.1 to 1.9V	21	24	-	dB
Noise Figure	NF _{LNA}	V _{CONT} =1.9V	-	1.3	1.6	dB
Pout at 1dB Gain Compression point	P _{-1dB}		+3.0	5.5	-	dBm
Input 3rd Order Intercept point	IIP3	V _{CONT} =1.9V ^{*1} V _{CONT} =0.1V ^{*1}	+2.0 +21.0	+4.0 +26.0	-	dBm dBm
RF IN VSWR	VSWR _i		-	2.0	2.5	
RF OUT VSWR	VSWR _o		-	1.5	2.0	

^{*1} Two tones of -30dBm each, f=850.0+850.1MHz

■ELECTRICAL CHARACTERISTICS 2 (Mixer)

GENERAL CONDITIONS: $T_a = +25^{\circ}\text{C}$, $V_{\text{MIX}} = V_{\text{LO}} = 2.8\text{V}$, $f_{\text{RF}} = 850\text{MHz}$, $f_{\text{LO}} = 740\text{MHz}$

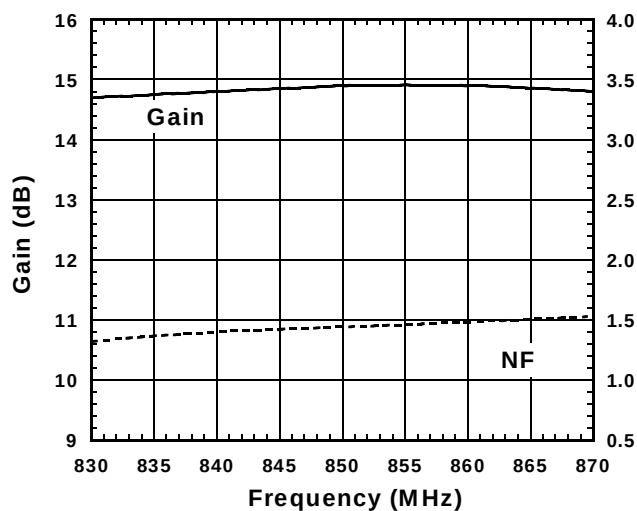
$P_{\text{RF}} = -30\text{dBm}$, $P_{\text{LO}} = -10\text{dBm}$, $Z_s = Z_i = 50\Omega$, with the test circuit

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Frequency	Freq		830	850	870	MHz
Mixer Voltage	V_{MIX}		2.7	2.8	4.5	V
Local Amplifier Voltage	V_{LO}		2.7	2.8	4.5	V
Mixer Current	I_{MIX}	$P_{\text{RF}}, P_{\text{LO}} = \text{OFF}$	-	7.5	9.1	mA
Local Current	I_{LO}	$P_{\text{RF}}, P_{\text{LO}} = \text{OFF}$		1.2	1.5	mA
Conversion Gain	G_c		8.5	10.0	-	dB
Noise Figure	NF_{MIX}		-	6.5	7.5	dB
Pout at 1dB Gain Compression point	$P_{-1\text{dB}}$		+0	+3.0	-	dBm
Input 3rd Order Intercept Point	IIP3	Two tone of -30dBm each $f_{\text{RF}} = 881.0 + 881.1\text{MHz}$	+4.0	+6.0	-	dBm
Lo to RF Isolation	ISL1		5	10	-	dB
Lo to IF Isolation	ISL2		25	30		dB
MIXER IN VSWR	VSWR_{MIX}		-	1.5	2.0	
LOCAL IN VSWR	VSWR_{LO}		-	1.5	2.0	
IF OUT VSWR	VSWR_{IF}		-	1.5	2.0	

NJG1712KC1

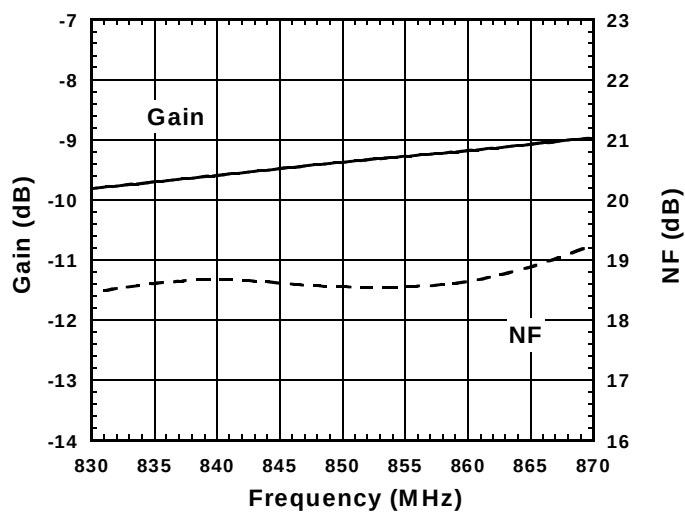
■ TYPICAL CHARACTERISTICS (LNA, with test circuit)

Gain, NF vs. Frequency



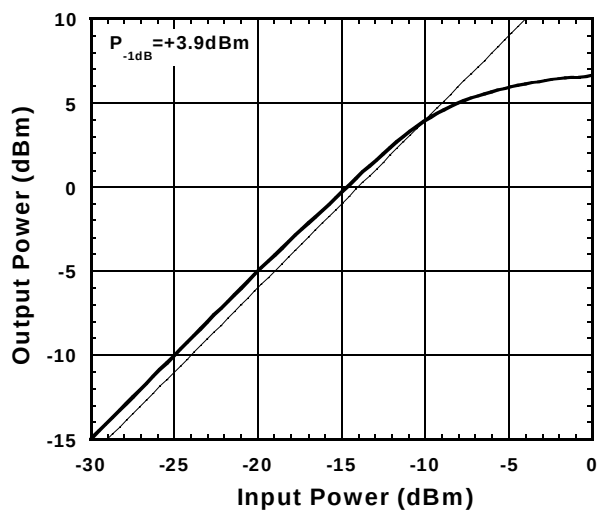
Condition
 $f=830\sim870\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Gain, NF vs. Frequency



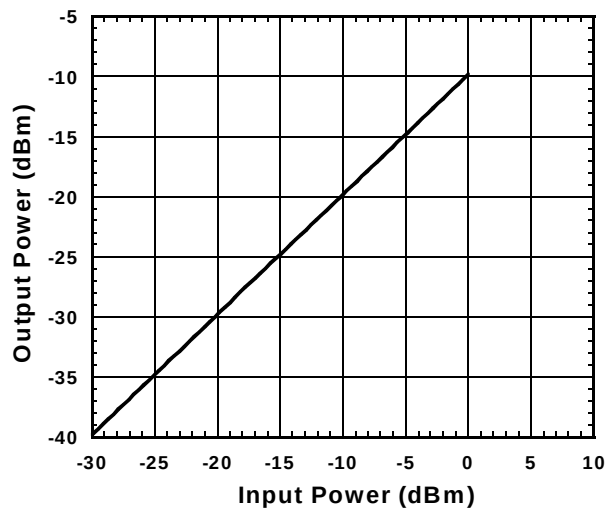
Condition
 $f=830\sim870\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Output Power vs. Input Power



Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

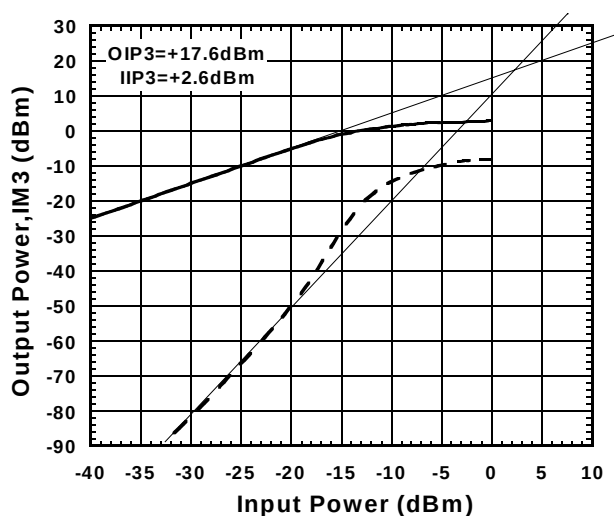
Output Power vs. Input Power



Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

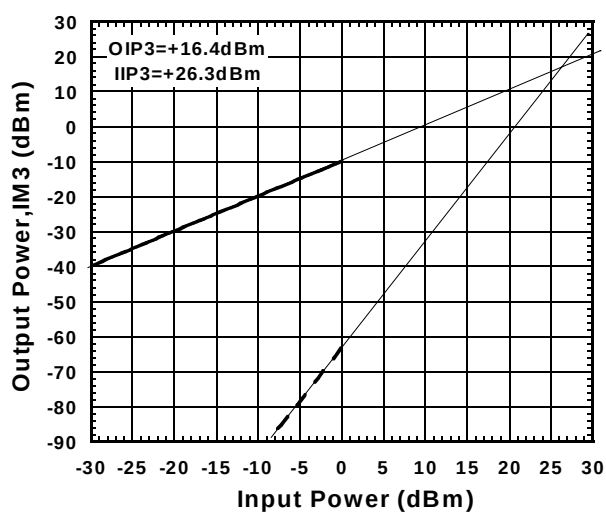
■ TYPICAL CHARACTERISTICS (LNA, with test circuit)

Output Power, IM3 vs. Input Power



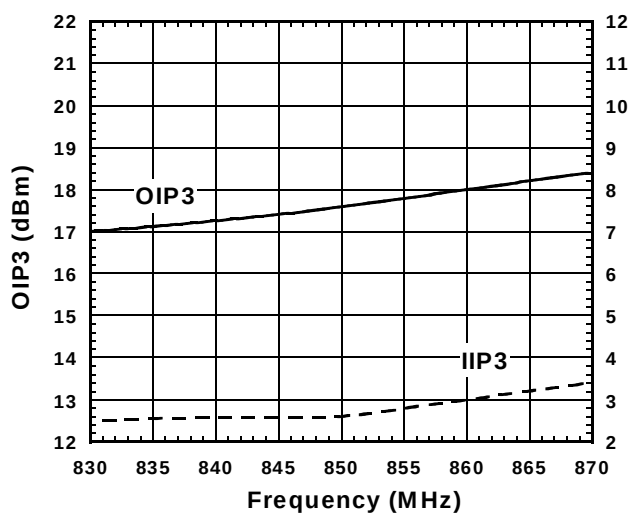
Condition
 $f=850+850.1\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Output Power, IM3 vs. Input Power



Condition
 $f=850+850.1\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

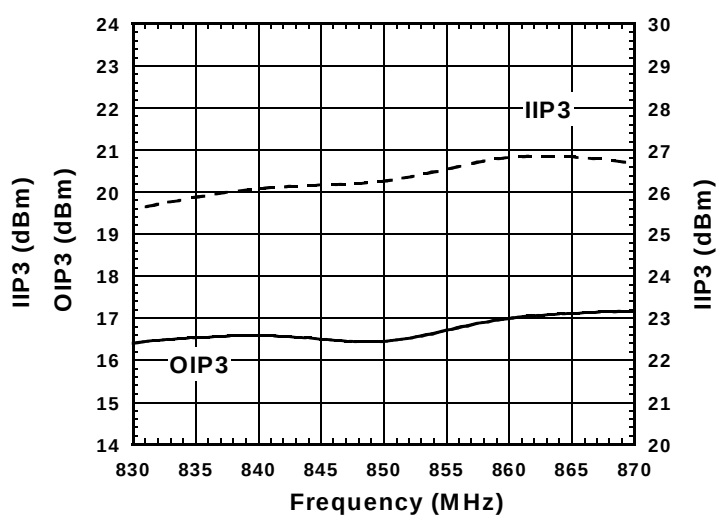
OIP3, IIP3 vs. Frequency



Condition
 $f=830\sim 870\text{MHz}$
 $f_{\text{OFFSET}}=100\text{kHz}$
 $\text{Pin}=-30\text{dBm}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

$\text{OIP3}=(3 \times \text{Pout}-\text{IM3})/2$
 $\text{IIP3}=\text{OIP3}-\text{Gain}$

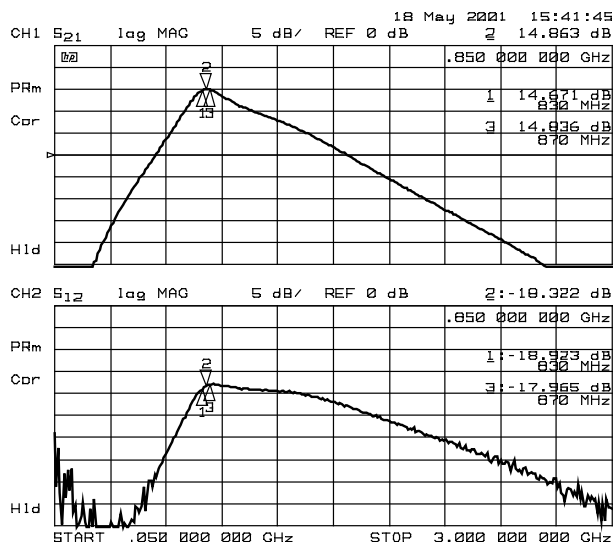
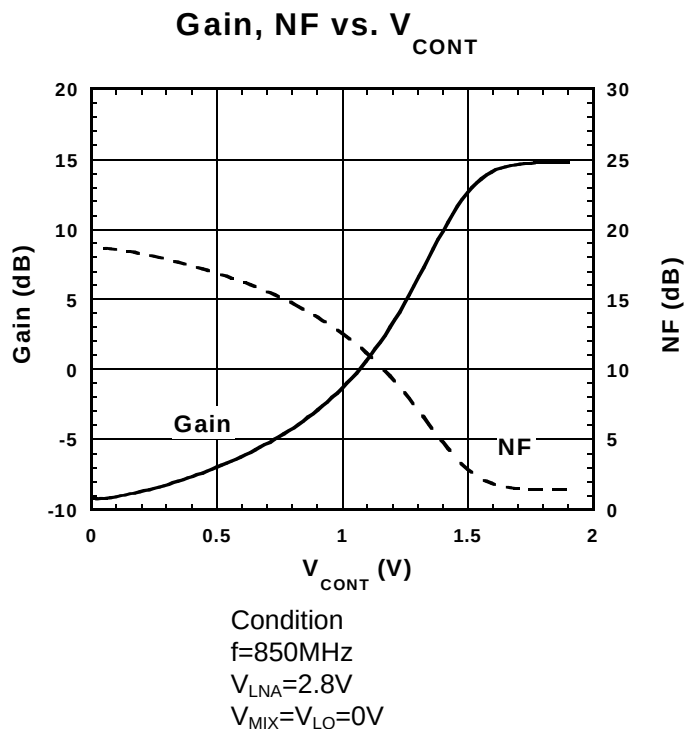
OIP3, IIP3 vs. Frequency



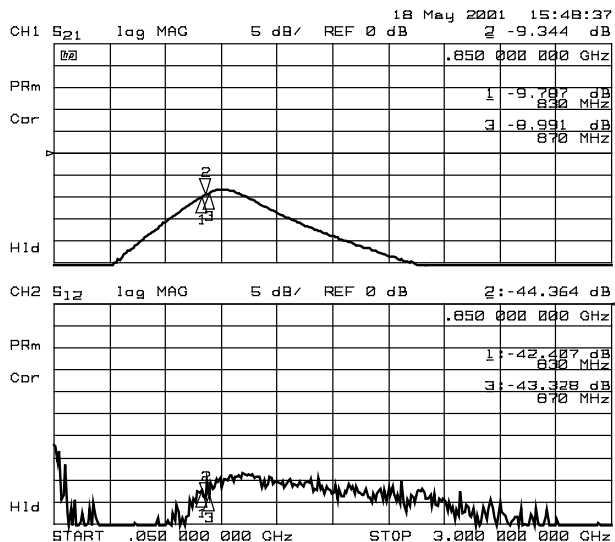
Condition
 $f=830\sim 870\text{MHz}$
 $f_{\text{OFFSET}}=100\text{kHz}$
 $\text{Pin}=-10\text{dBm}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

NJG1712KC1

■ TYPICAL CHARACTERISTICS (LNA, with test circuit)

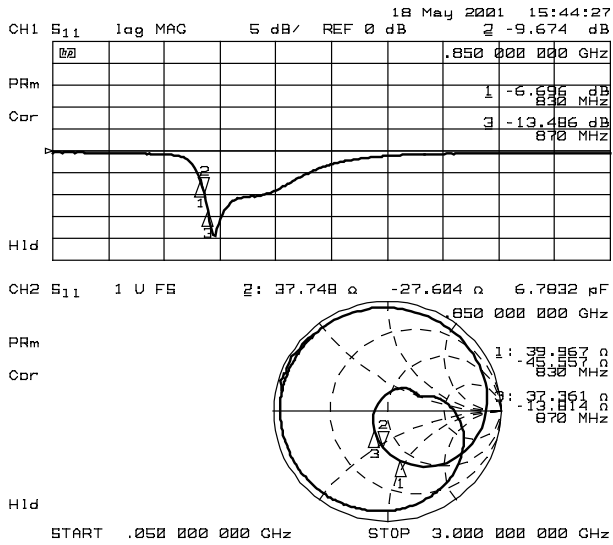


S₂₁&S₁₂
 Condition
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

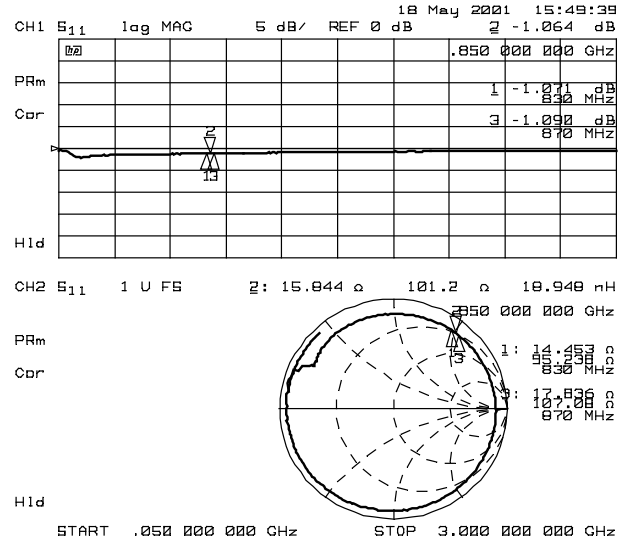


S₂₁&S₁₂
 Condition
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

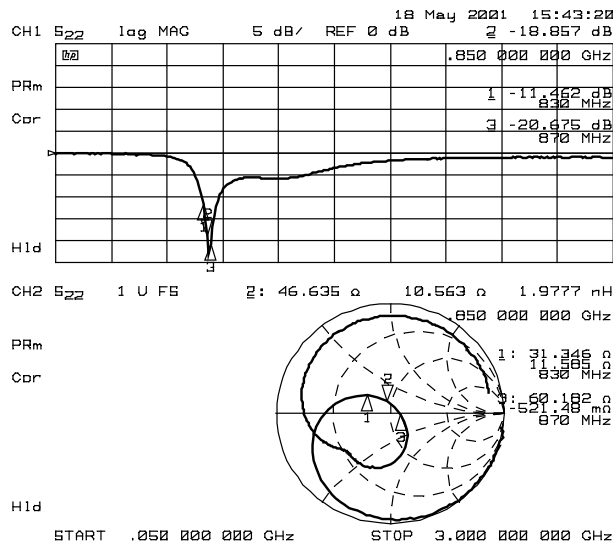
TYPICAL CHARACTERISTICS (LNA, with test circuit)



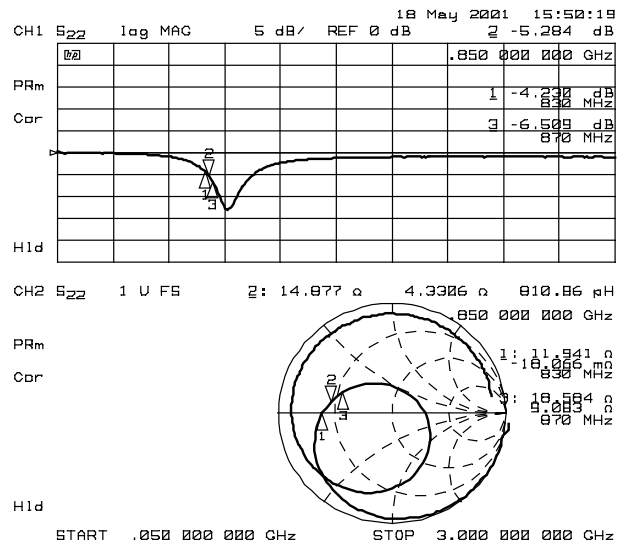
RF IN port Impedance
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=1.9V$
 $V_{MIX}=V_{LO}=0V$



RF IN port Impedance
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=0.1V$
 $V_{MIX}=V_{LO}=0V$

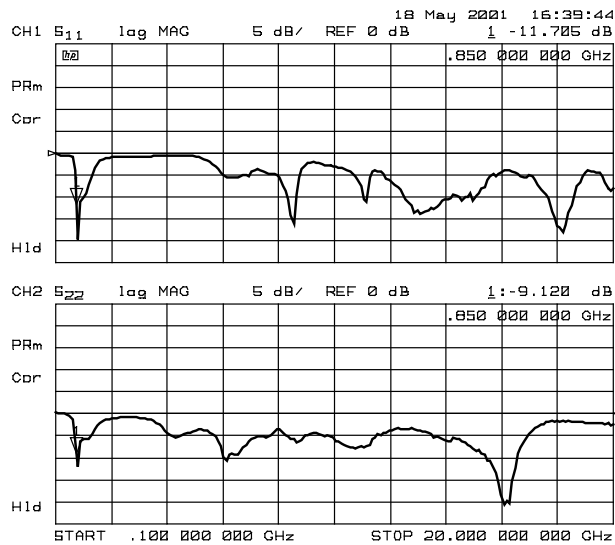


RF OUT port Impedance
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=1.9V$
 $V_{MIX}=V_{LO}=0V$

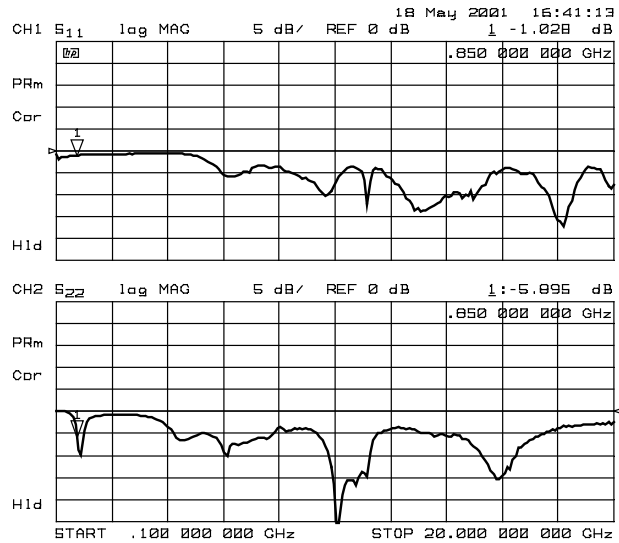


RF OUT port Impedance
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=0.1V$
 $V_{MIX}=V_{LO}=0V$

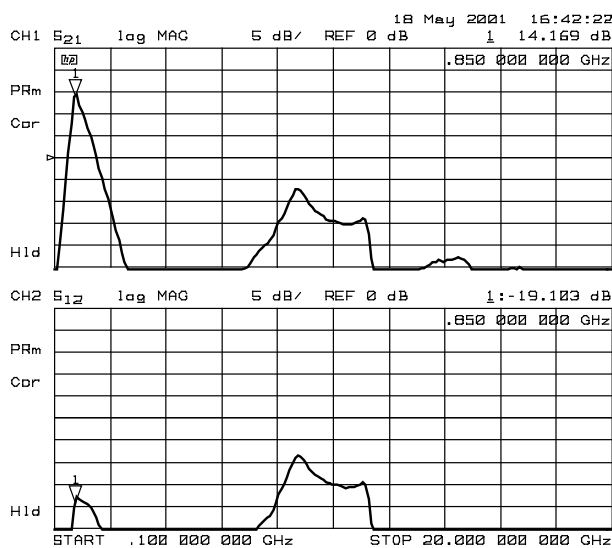
■ TYPICAL CHARACTERISTICS (LNA, with test circuit)



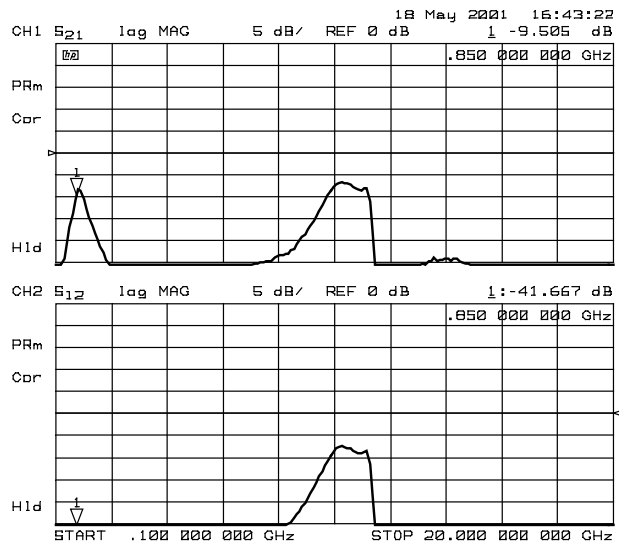
S₁₁&S₂₂ (~20GHz)
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=1.9V$
 $V_{MIX}=V_{LO}=0V$



S₁₁&S₂₂ (~20GHz)
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=0.1V$
 $V_{MIX}=V_{LO}=0V$



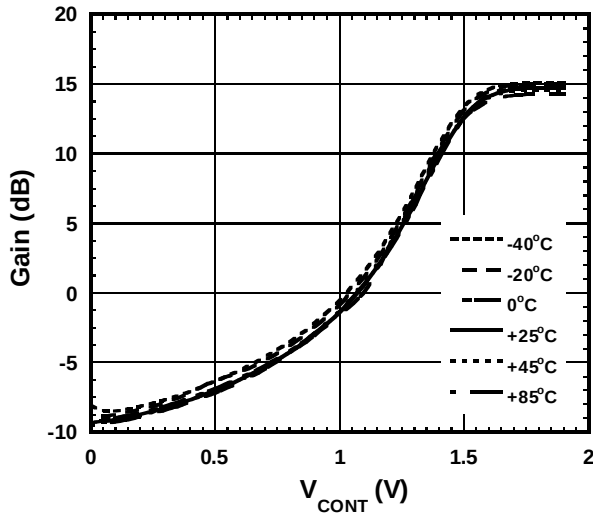
S₂₁&S₁₂ (~20GHz)
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=1.9V$
 $V_{MIX}=V_{LO}=0V$



S₂₁&S₁₂ (~20GHz)
Condition
 $V_{LNA}=2.8V$, $V_{CONT}=0.1V$
 $V_{MIX}=V_{LO}=0V$

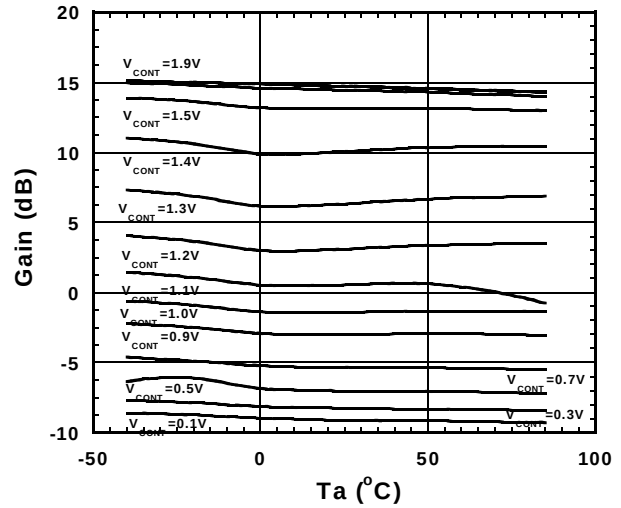
■ TYPICAL CHARACTERISTICS (LNA, with test circuit)

Gain vs. V_{CONT} (Variable T_a)



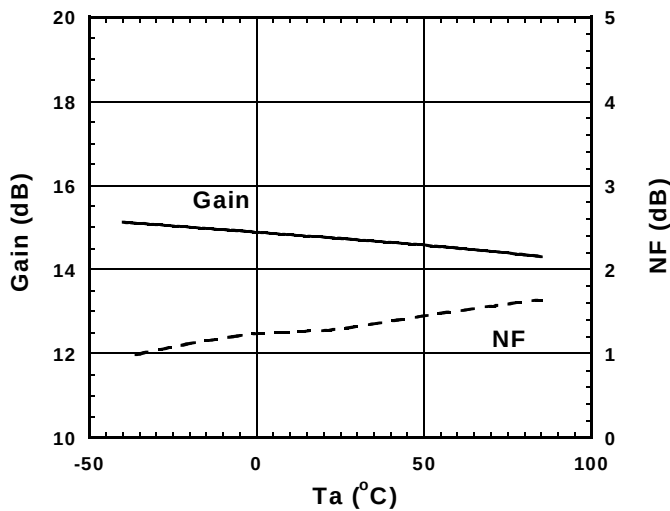
Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Gain vs. T_a (Variable V_{CONT})



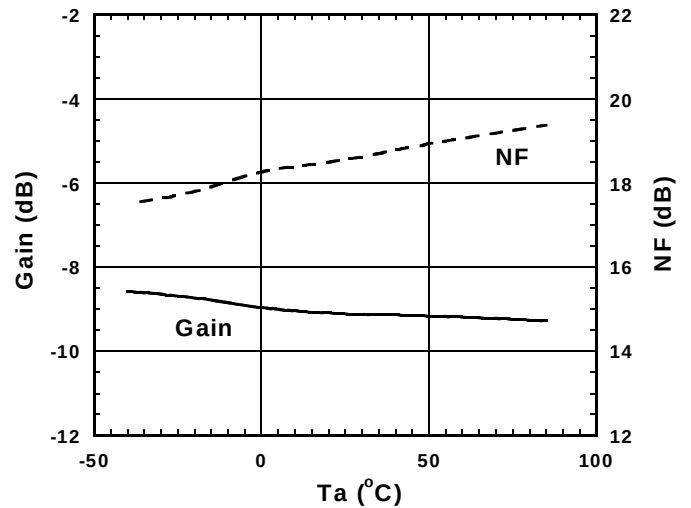
Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Gain, NF vs. T_a



Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

Gain, NF vs. T_a

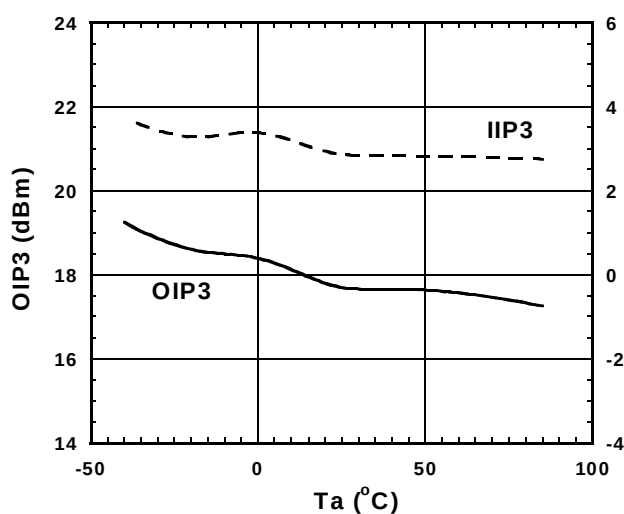


Condition
 $f=850\text{MHz}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

NJG1712KC1

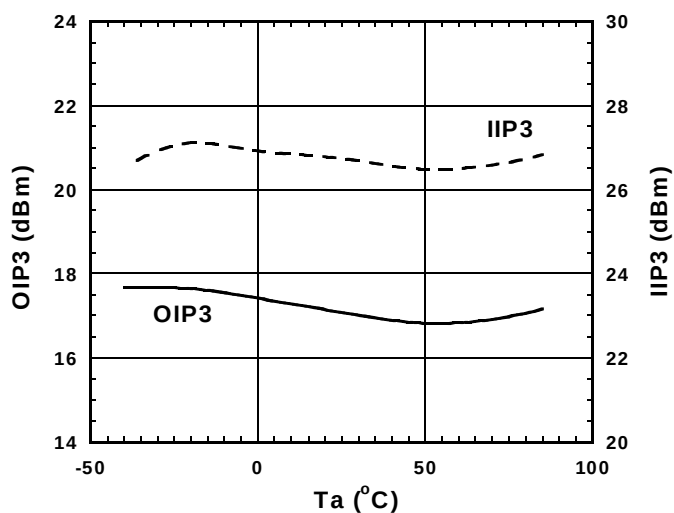
■ TYPICAL CHARACTERISTICS (LNA, with test circuit)

OIP3, IIP3 vs. Ta



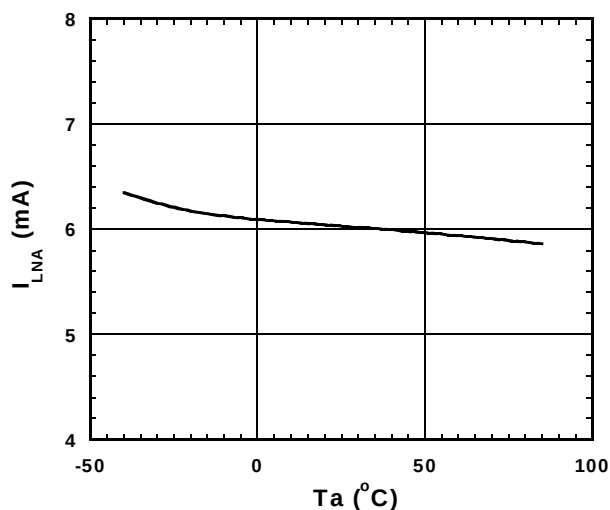
Condition
 $f=850+850.1\text{MHz}$
 $\text{Pin}=-10\text{dBm}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

OIP3, IIP3 vs. Ta



Condition
 $f=850+850.1\text{MHz}$
 $\text{Pin}=-10\text{dBm}$
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=0.1\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

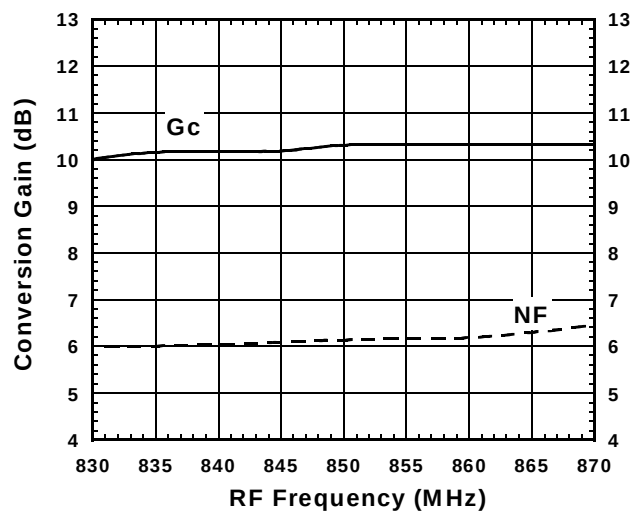
I_{LNA} vs. Ta



Condition
 $V_{\text{LNA}}=2.8\text{V}$, $V_{\text{CONT}}=1.9\text{V}$
 $V_{\text{MIX}}=V_{\text{LO}}=0\text{V}$

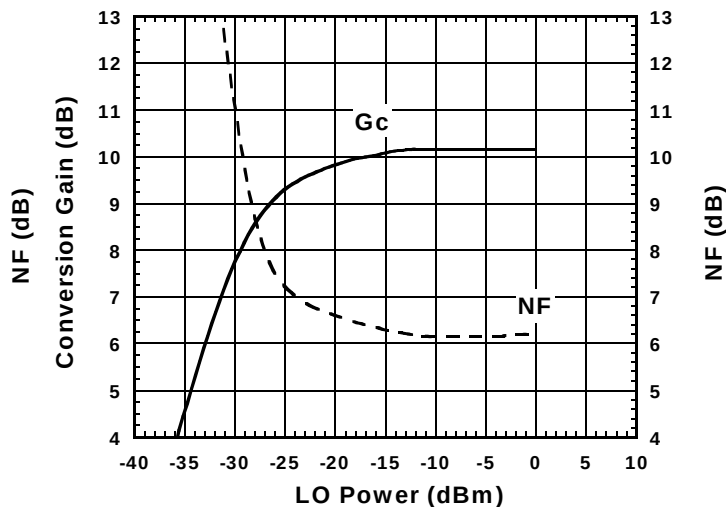
■ TYPICAL CHARACTERISTICS (MIXER, with test circuit)

Gc, NF vs. RF Frequency



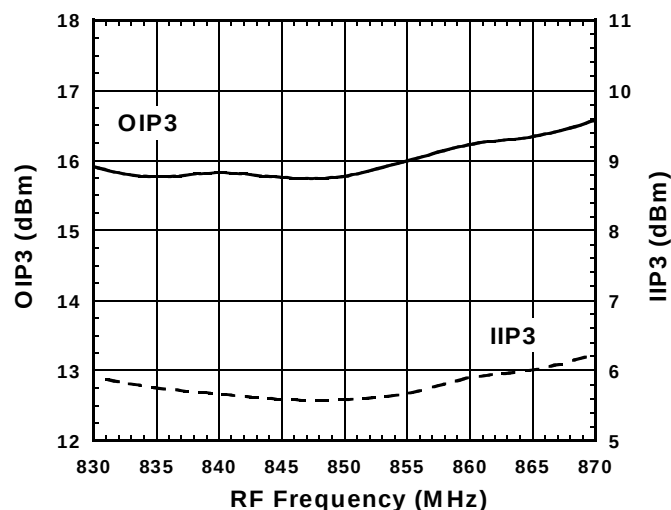
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=830\sim 870\text{MHz}$, $P_{RF}=-25\text{dBm}$
 Lower LOCAL, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

Gc, NF vs. LO Power



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{LO}=740\text{MHz}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

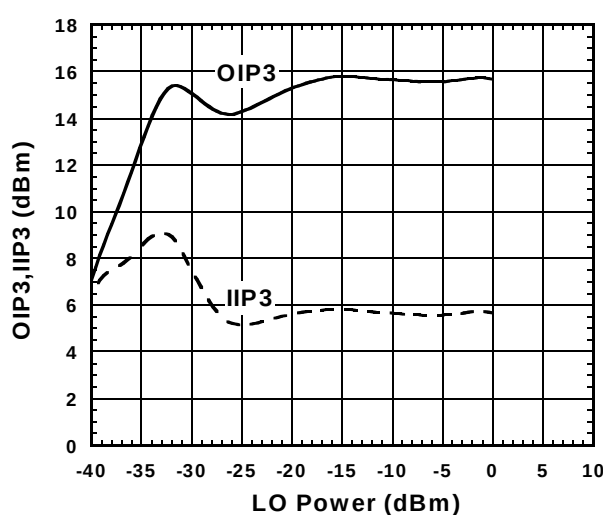
OIP3, IIP3 vs. RF Frequency



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=830\sim 870\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{RF\text{ OFFSET}}=100\text{kHz}$
 Lower LOCAL, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

$OIP3=(3 \times IF - IM3)/2$
 $IIP3=OIP3 - Gc$

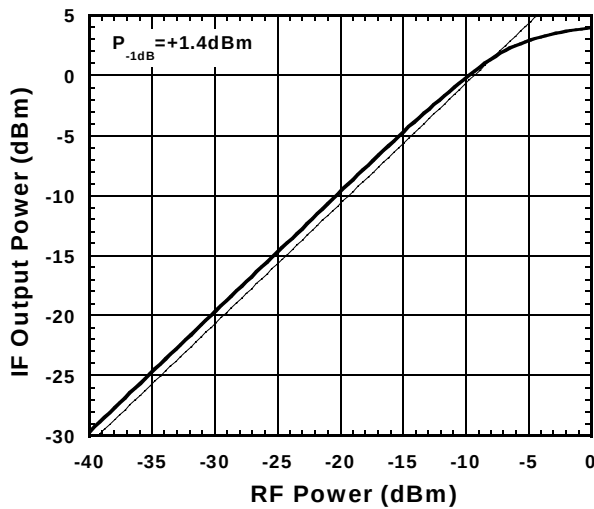
OIP3, IIP3 vs. LO Power



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850+850.1\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{LO}=740\text{MHz}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

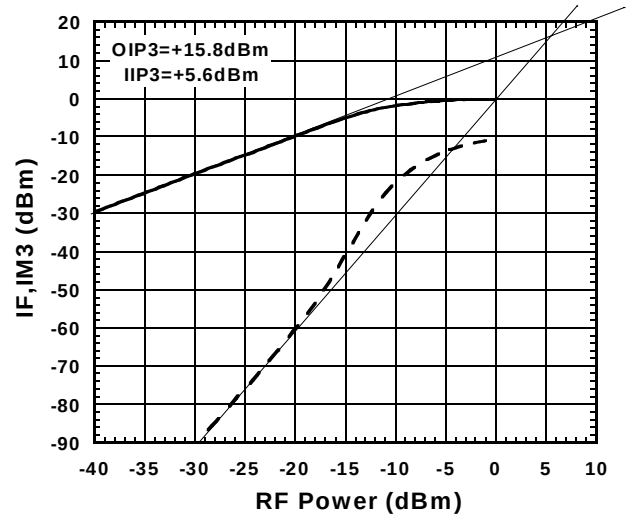
■ TYPICAL CHARACTERISTICS (MIXER, with test circuit)

IF Output Power vs. RF Power



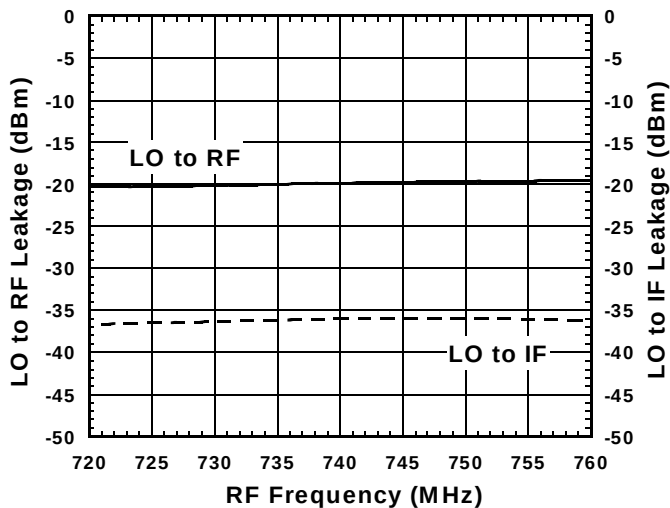
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850\text{MHz}$
 $f_{LO}=740\text{MHz}$, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

IF,IM3 vs. RF Power



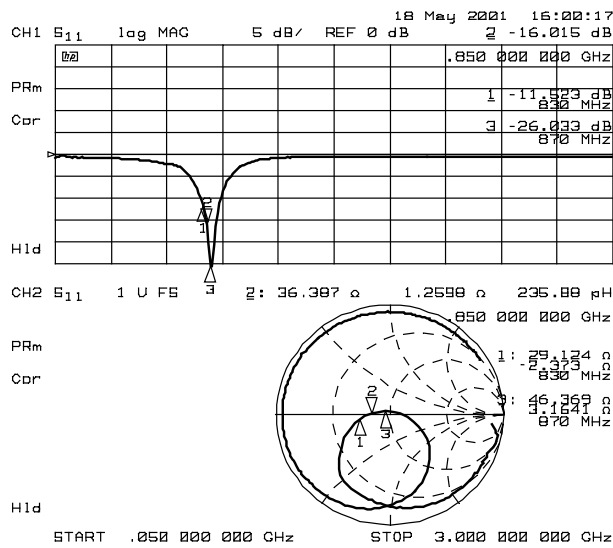
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850+850.1\text{MHz}$
 $f_{LO}=740\text{MHz}$, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

LO Leakage vs. LO Frequency



Condition
 $f_{LO}=720\sim 760\text{MHz}$, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

TYPICAL CHARACTERISTICS (MIXER, with test circuit)



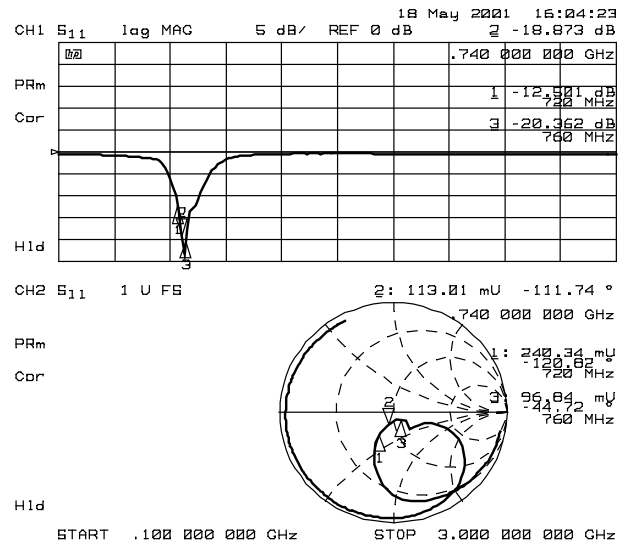
MIXER IN Impedance

Condition

LOCAL IN, IF OUT 50 Ω term.

V_{LNA}=V_{CONT}=0V

V_{MIX}=V_{LO}=2.8V



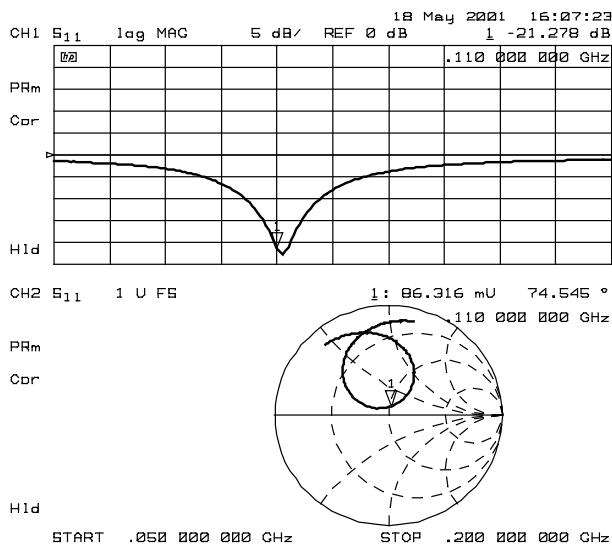
LOCAL IN Impedance

Condition

MIXER IN, IF OUT 50 Ω term.

V_{LNA}=V_{CONT}=0V

V_{MIX}=V_{LO}=2.8V



IF OUT Impedance

Condition

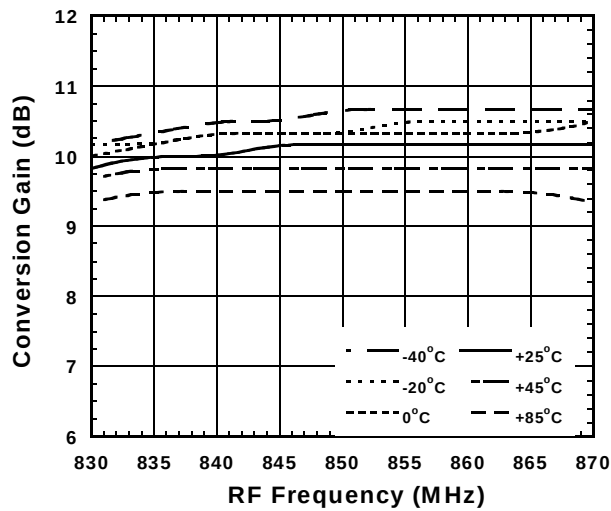
MIXER IN, LOCAL IN 50 Ω term.

V_{LNA}=V_{CONT}=0V

V_{MIX}=V_{LO}=2.8V

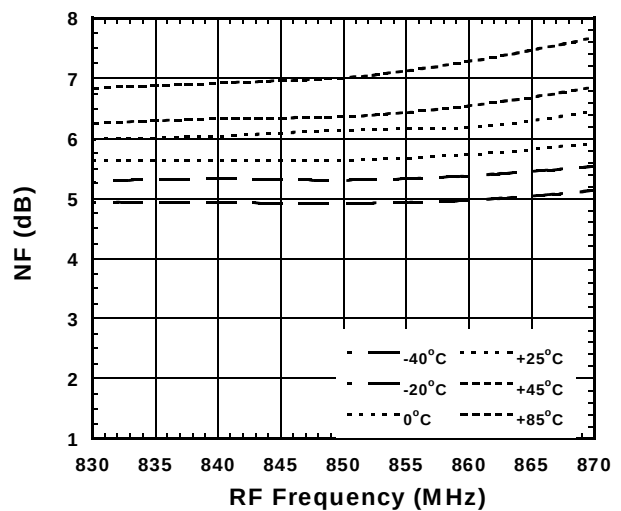
■ TYPICAL CHARACTERISTICS (MIXER, with test circuit)

Conversion Gain vs. RF Frequency



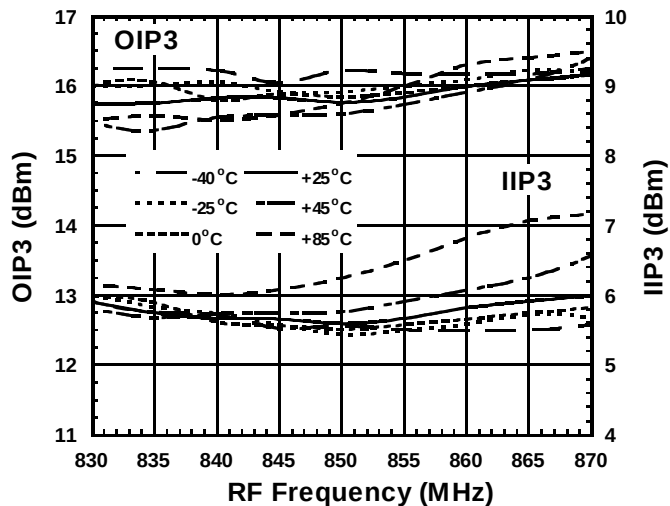
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=830\sim 870\text{MHz}$, $P_{RF}=-25\text{dBm}$
 Lower LOCAL, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

NF vs. RF Frequency



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=830\sim 870\text{MHz}$, $P_{RF}=-25\text{dBm}$
 Lower LOCAL, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

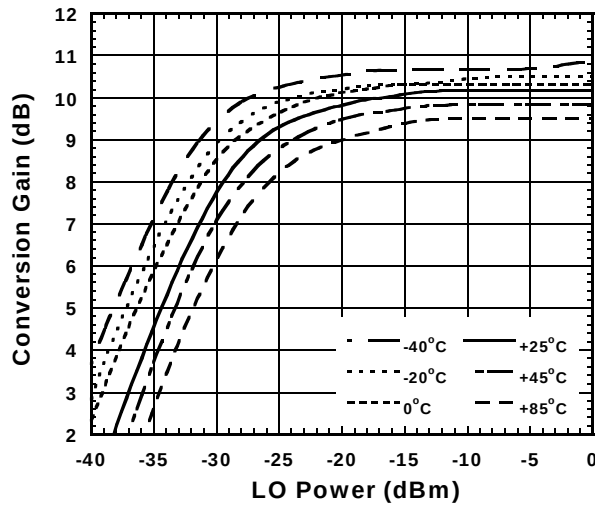
OIP3, IIP3 vs. RF Frequency



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=830\sim 870\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{RF\text{ OFFSET}}=100\text{kHz}$
 Lower LOCAL, $P_{LO}=-10\text{dBm}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

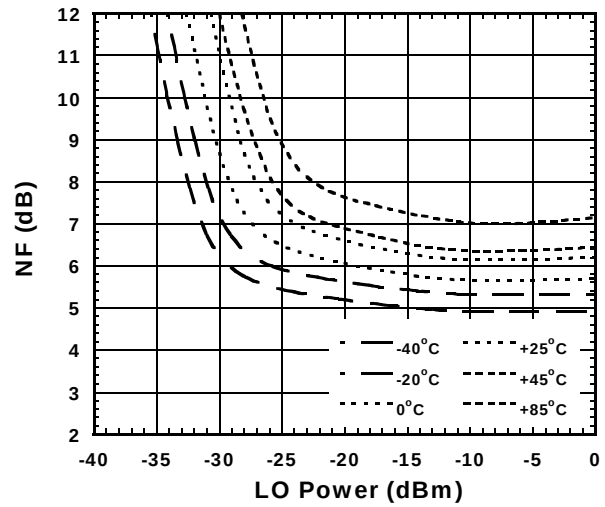
TYPICAL CHARACTERISTICS (MIXER, with test circuit)

Conversion Gain vs. Lo Power



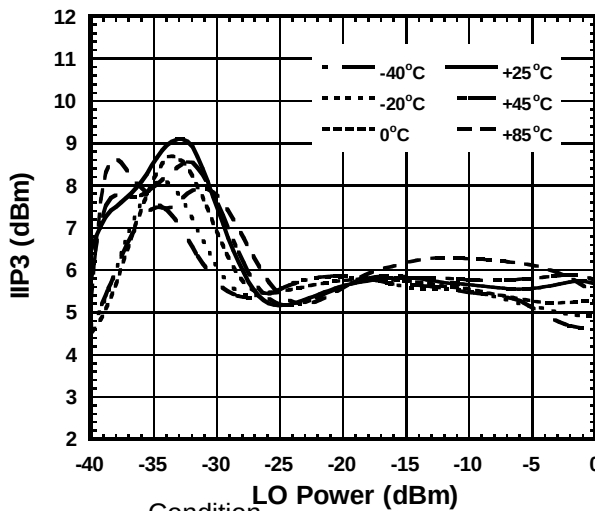
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{LO}=740\text{MHz}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

NF vs. LO Power



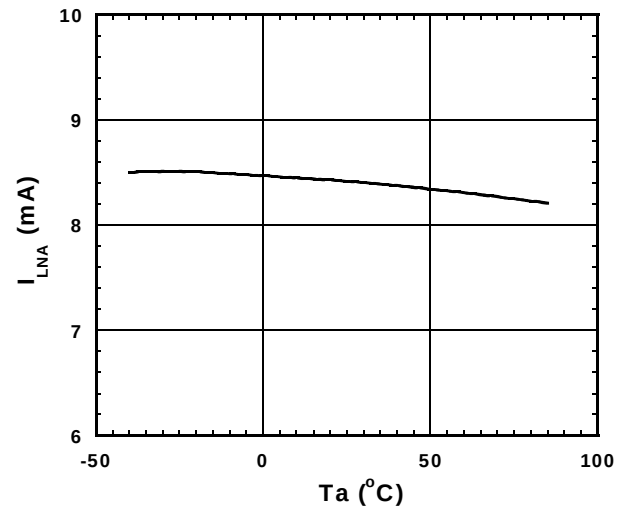
Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{LO}=740\text{MHz}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

IIP3 vs. LO Power



Condition
 $f_{IF}=110\text{MHz}$
 $f_{RF}=850+850.1\text{MHz}$, $P_{RF}=-25\text{dBm}$
 $f_{LO}=740\text{MHz}$
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

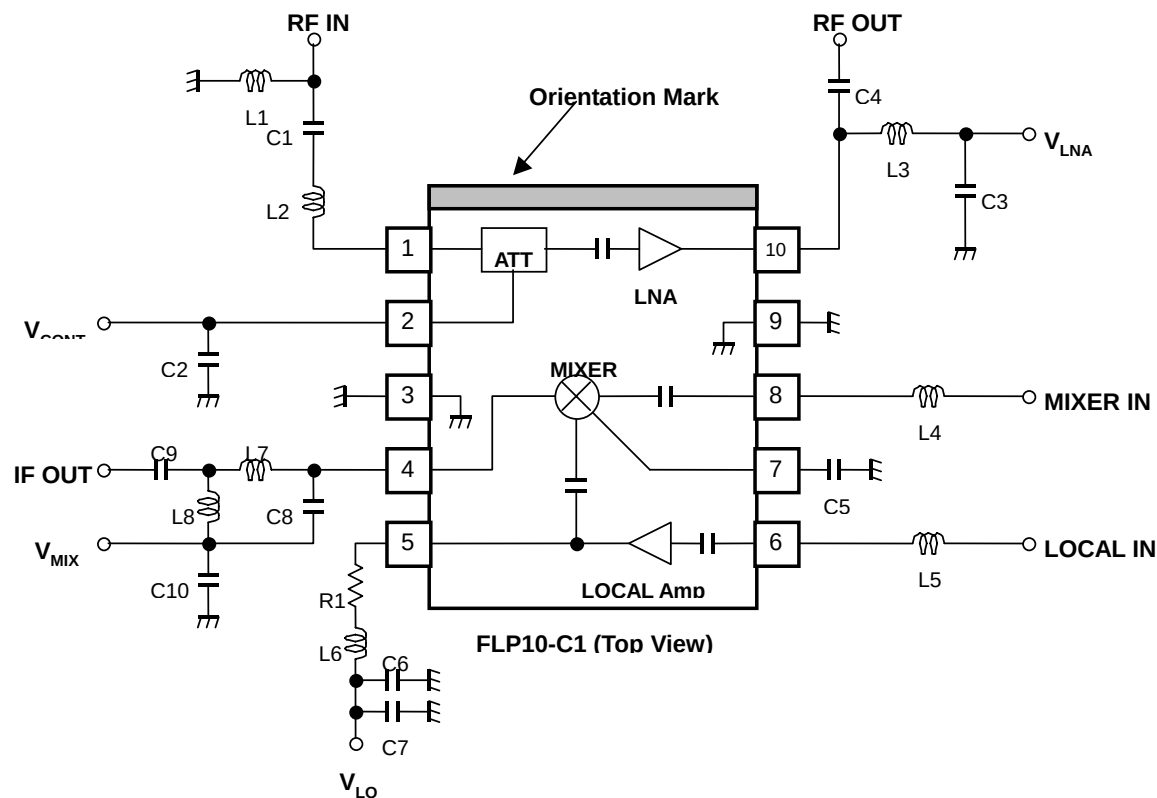
I_{TOTAL} vs. T_a



Condition
 $V_{LNA}=V_{CONT}=0\text{V}$
 $V_{MIX}=V_{LO}=2.8\text{V}$

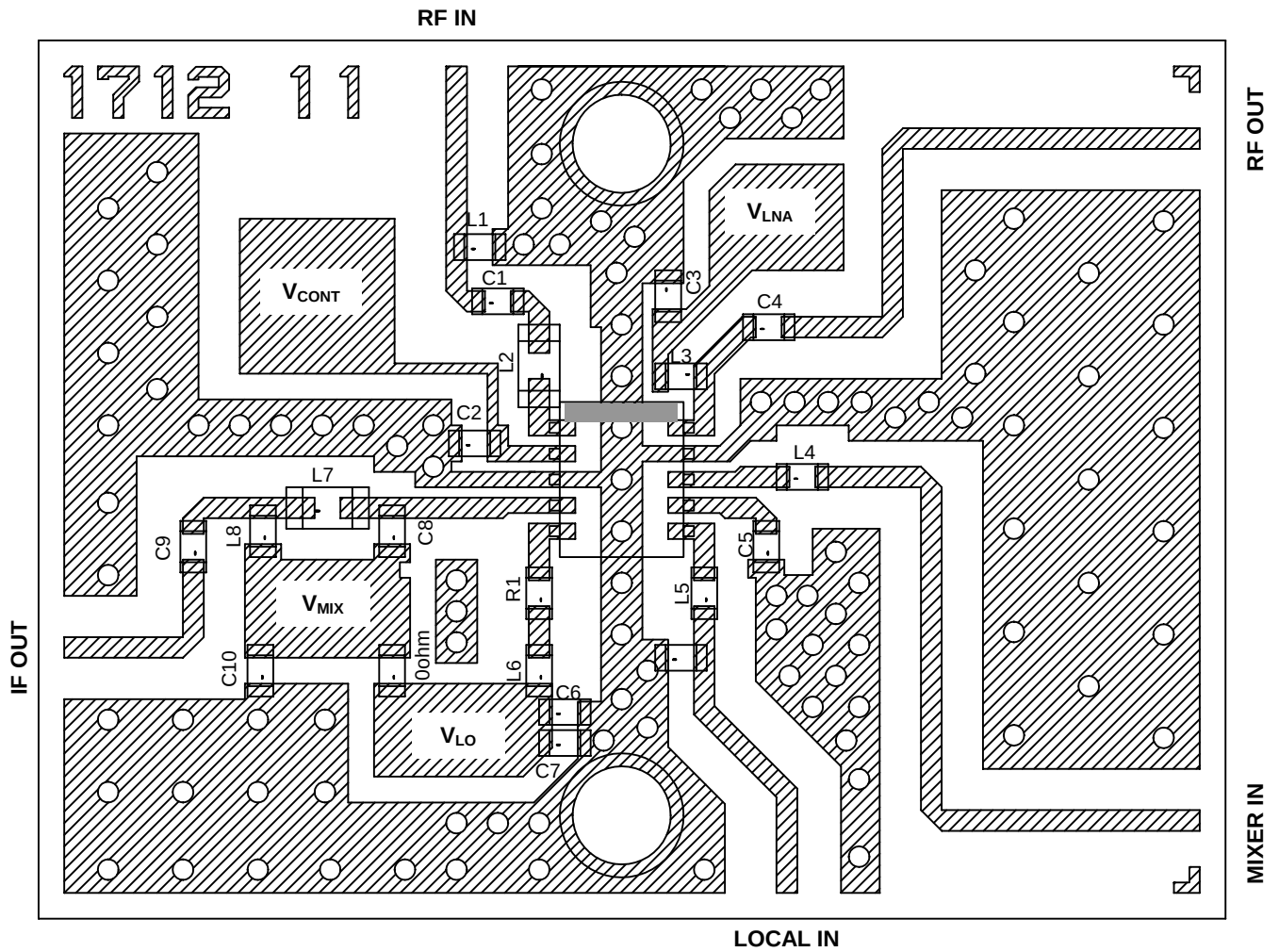
NJG1712KC1

■ TEST CIRCUIT



PART ID	850MHzBAND	COMMENT
	Lower LOCAL	
	$f_{LO}=740\text{MHz}$, $f_{IF}=110\text{MHz}$	
L1	12nH	TAIYO-YUDEN (HK1005)
L2	18nH	TAIYO-YUDEN (HK1608)
L3	12nH	TAIYO-YUDEN (HK1005)
L4	33nH	TAIYO-YUDEN (HK1005)
L5	47nH	TAIYO-YUDEN (HK1005)
L6	33nH	TAIYO-YUDEN (HK1005)
L7	150nH	TAIYO-YUDEN (HK1608)
L8	68nH	TAIYO-YUDEN (HK1005)
C1	1000pF	MURATA (GRM36)
C2	1000pF	MURATA (GRM36)
C3	0.01uF	MURATA (GRM36)
C4	1.5pF	MURATA (GRM36)
C5	100pF	MURATA (GRM36)
C6	100pF	MURATA (GRM36)
C7	0.01uF	MURATA (GRM36)
C8	8pF	MURATA (GRM36)
C9	1000pF	MURATA (GRM36)
C10	0.01uF	MURATA (GRM36)
R1	10 Ω	1005 Size

RECOMMENDED PCB DESIGN



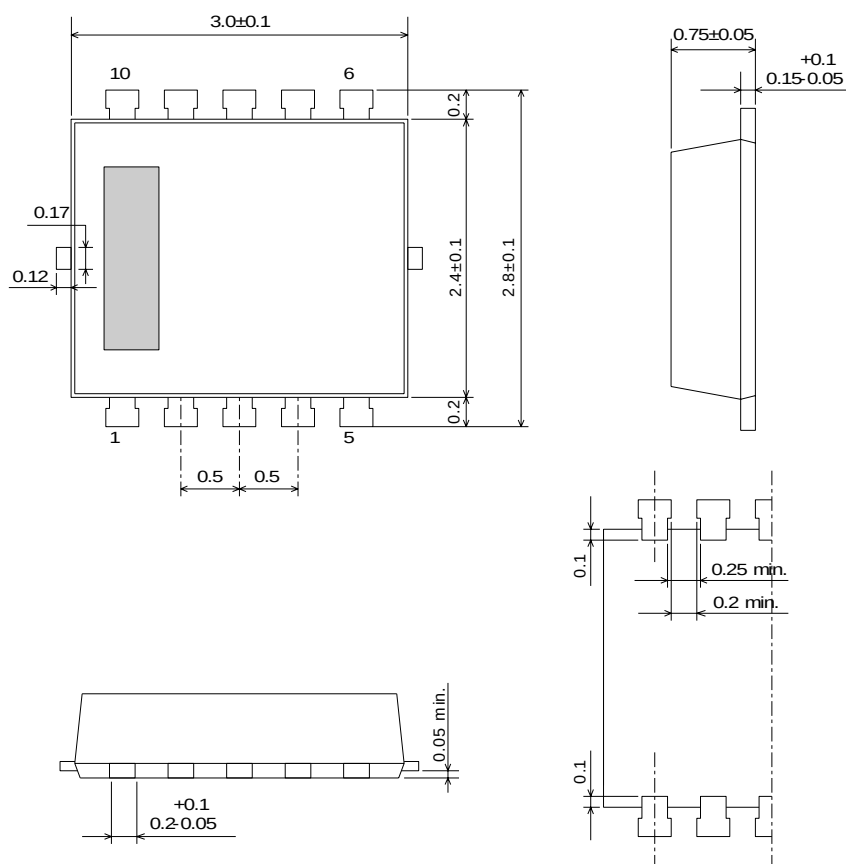
PCB (FR-4): $t=0.2\text{mm}$

MICRO STRIPLINE WIDTH= 0.4mm ($Z_0=50\Omega$)

PCB SIZE= $23.0\times 17.0\text{ mm}$

NJG1712KC1

■PACKAGE OUTLINE (FLP10-C1)



Lead material : Copper
 Lead surface finish : Solder plating
 Molding material : Epoxy resin
 UNIT : mm
 Weight : 15mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.